











SN74AHC541, SN54AHC541

SCLS261O - OCTOBER 1995-REVISED SEPTEMBER 2015

SNx4AHC541 Octal Buffers/Drivers With 3-State Outputs

Features

- Operating Range 2-V to 5.5-V V_{CC}
- Latch-Up Performance Exceeds 250 mA Per JESD 17
- On Products Compliant to MIL-PRF-38535, All Parameters Are Tested Unless Otherwise Noted. On All Other Products, Production Processing Does Not Necessarily Include Testing of All Parameters.

2 Applications

- Servers
- PCs and Notebooks
- **Network Switches**
- Wearable Health and Fitness Devices
- Telecom Infrastructures
- Electronic Points-of-Sale

3 Description

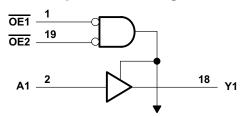
The SNx4AHC541 octal buffers and drivers are ideal for driving bus lines or buffer memory address registers. These devices feature inputs and outputs on opposite sides of the package to facilitate printed circuit board layout.

Device Information⁽¹⁾

PART NUMBER	PACKAGE	BODY SIZE (NOM)			
SNx4AHC541N	PDIP (20)	25.40 mm x 6.35 mm			
SNx4AHC541DB	SSOP (20)	7.50 mm x 5.30 mm			
SNx4AHC541PW	TSSOP (20)	6.50 mm x 4.40 mm			
SNx4AHC541DGV	TVSOP (20)	5.00 mm x 4.40 mm			
SNx4AHC541DW	SOIC (20)	12.80 mm x 7.50 mm			

(1) For all available packages, see the orderable addendum at the end of the data sheet.

Simplified Block Diagram



To Seven Other Channels



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4 Revision History

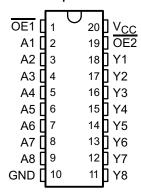
Changes from Revision N (July 2003) to Revision O

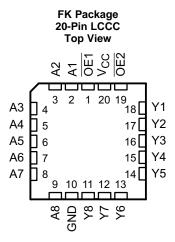
Page



5 Pin Configuration and Functions

N, DB, PW, DGV, or DW Package 20-Pin PDIP, SSOP, TSSOP, TVSOP, SOIC Top View





Pin Functions

P	IN	1/0	DESCRIPTION
NO.	NAME	I/O	DESCRIPTION
1	OE1	I	Output Enable 1
2	A1	1	A1 Input
3	A2	1	A2 Input
4	A3	1	A3 Input
5	A4	1	A4 Input
6	A5	I	A5 Input
7	A6	1	A6 Input
8	A7	1	A7 Input
9	A8	1	A8 Input
10	GND	_	Ground
11	Y8	0	Y8 Output
12	Y7	0	Y7 Output
13	Y6	0	Y6 Output
14	Y5	0	Y5 Output
15	Y4	0	Y4 Output
16	Y3	0	Y3 Output
17	Y2	0	Y2 Output
18	Y1	0	Y1 Output
19	OE2	1	Output Enable 2
20	V _{CC}	_	Power Pin

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6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

			MIN	MAX	UNIT
V_{CC}	Supply voltage		-0.5	7	٧
VI	Input voltage ⁽²⁾		-0.5	7	V
Vo	Output voltage ⁽²⁾				
I _{IK}	Input clamp current	V _I < 0		-20	mA
I _{OK}	Output clamp current	$V_O < 0$ or $V_O > V_{CC}$		±20	mA
Io	Continuous output current	$V_O = 0$ to V_{CC}		±25	mA
	Continuous current through V _{CC} or GND		±75	mA	
T _{stg}	Storage temperature		-65	150	°C

⁽¹⁾ Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

6.2 ESD Ratings

			VALUE	UNIT
\/	Floatroototic disabores	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins (1)	+1000	V
V _(ESD)	Electrostatic discharge	Charged-device model (CDM), per JEDEC specification JESD22-C101, all pins (2)	+2000	V

⁽¹⁾ JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)(1)

			SN54AH	C541	SN74AH	C541	LINUT	
			MIN	MAX	MIN	MAX	UNIT	
V _{CC}	Supply voltage		2	5.5	2	5.5	V	
		V _{CC} = 2 V	1.5		1.5			
V_{IH}	High-level input voltage	$V_{CC} = 3 V$	2.1		2.1		V	
		V _{CC} = 5.5 V	3.85		3.85			
		V _{CC} = 2 V		0.5		0.5		
V_{IL}	Low-level Input voltage	V _{CC} = 3 V		0.9		0.9		
		V _{CC} = 5.5 V		1.65		1.65		
V_{I}	Input voltage		0	5.5	0	5.5	V	
Vo	Output voltage		0	V _{CC}	0	V _{CC}	V	
		V _{CC} = 2 V		-50		-50	μΑ	
I _{OH}	High-level output current	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		-4		-4	1	
		$V_{CC} = 5 V \pm 0.5 V$		-8		-8	mA	
		V _{CC} = 2 V		50		50	μΑ	
I _{OL}	Low-level output current	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		4		4	Λ	
		$V_{CC} = 5 V \pm 0.5 V$		8		8	mA	
A+/A.,	langet transition rise or fell rate	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		100		100	20/1	
Δt/Δv	Input transition rise or fall rate	$V_{CC} = 5 V \pm 0.5 V$		20		20	ns/V	
T _A	Operating free-air temperature		-55	125	-40	125	°C	

⁽¹⁾ All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs (SCBA004).

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⁽²⁾ The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

⁽²⁾ JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.



6.4 Thermal Information

				SN74A	HC541			
	THERMAL METRIC ⁽¹⁾	DB (SSOP)	DGV (TVSOP)	DW (SOIC)	N (PDIP)	NS (SO)	PW (TSSOP)	UNIT
		20 PINS	20 PINS	20 PINS	20 PINS	20 PINS	20 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	99.9	119.2	83.0	54.9	80.4	105.4	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	61.7	34.5	48.9	41.7	46.9	39.5	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	55.2	60.7	50.5	35.8	47.9	56.4	°C/W
ΨЈТ	Junction-to-top characterization parameter	22.6	1.2	21.1	27.9	19.9	3.1	°C/W
ΨЈВ	Junction-to-board characterization parameter	54.8	60.0	50.1	35.7	47.5	55.8	°C/W

⁽¹⁾ For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report (SPRA953).

6.5 Electrical Characteristics

over operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V _{cc}	T _A = 25°C		SN54AHC541		SN74AHC541		SN74AHC541 -40°C to 125°C		UNIT	
			MIN	TYP	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
		2 V	1.9	2		1.9		1.9		1.9		
	$I_{OH} = -50 \mu A$	3 V	2.9	3		2.9		2.9		2.9		
V _{OH}		4.5 V	4.4	4.5		4.4		4.4		4.4		V
	I _{OH} = -4 mA	3 V	2.58			2.48		2.48		2.48		
	I _{OH} = -8 mA	4.5 V	3.94			3.8		3.8		3.8		
		2 V			0.1		0.1		0.1		0.1	
	$I_{OL} = 50 \mu A$	3 V			0.1		0.1		0.1		0.1	
V _{OL}		4.5 V			0.1		0.1		0.1		0.1	V
	I _{OH} = 4 mA	3 V			0.36		0.5		0.44		0.5	
	I _{OH} = 8 mA	4.5 V			0.36		0.5		0.44		0.5	
I	V _I = 5.5 V or GND	0 V to 5.5 V			±0.1		±1 ⁽¹⁾		±1		±1	μΑ
I _{OZ} ⁽²⁾	$V_O = V_{CC}$ or GND $V_I (\overline{OE}) = V_{IL}$ or V_{IH}	5.5 V			±0.25		±2.5		±2.5		±2.5	μA
I _{cc}	$V_I = V_{CC}$ or GND $I_O = 0$	5.5 V			4		40		40		20	μΑ
C _i	$V_I = V_{CC}$ or GND	5 V		2	10				10			pF
Co	$V_O = V_{CC}$ or GND	5 V		4								pF

⁽¹⁾ On products compliant to MIL-PRF-38535, this parameter is not production tested at $V_{CC} = 0 \text{ V}$. (2) For input and output pins, I_{OZ} includes the input leakage current.



6.6 Switching Characteristics, $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 2)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	LOAD CAPACITANCE	T _A = 2	5°C	SN54AH	IC541	SN74A	HC541	SN74AH0 T _A = -40°C to		UNIT		
	(INFOI)	(001701)	CAFACITANCE	TYP	MAX	MIN	MAX	MIN	MAX	MIN	MAX			
t _{PLH}	Α	Υ	0 45 25	5 ⁽¹⁾	7 ⁽¹⁾	1 ⁽¹⁾	8.5 ⁽¹⁾	1	8.5	1	8.5			
t _{PHL}	Α	Y	$C_L = 15 pF$	5 ⁽¹⁾	7 ⁽¹⁾	1 ⁽¹⁾	8.5 ⁽¹⁾	1	8.5	1	8.5	ns		
t _{PZH}	ŌĒ	Y	0 45 25	6 ⁽¹⁾	10.5 ⁽¹⁾	1 ⁽¹⁾	11 ⁽¹⁾	1	11	1	11			
t _{PZL}	OE	Y	C _L = 15 pF	6 ⁽¹⁾	10.5 ⁽¹⁾	1 ⁽¹⁾	11 ⁽¹⁾	1	11	1	11	ns		
t _{PHZ}	ŌĒ	Υ	0 45 25	7 ⁽¹⁾	11 ⁽¹⁾	1 ⁽¹⁾	12 ⁽¹⁾	1	12	1	12			
t_{PLZ}	UE	OL	Y	C _L = 15 pF	7 ⁽¹⁾	11 ⁽¹⁾	1 ⁽¹⁾	12 ⁽¹⁾	1	12	1	12	ns	
t _{PLH}	Α	Υ	C 50 7 5	7.5	10.5	1	12	1	12	1	12			
t _{PHL}	A	Y	Y $C_L = 50 \text{ pF}$	7.5	10.5	1	12	1	12	1	12	ns		
t _{PZH}			ŌĒ	Y	C 50 7 5	8	14	1	16	1	16	1	16	
t _{PZL}	OE	Y	$C_L = 50 \text{ pF}$	8	14	1	16	1	16	1	16	ns		
t _{PHZ}	ŌĒ	Y	C ₁ = 50 pF	9	15.4	1	17.5	1	17.5	1	17.5	no		
t _{PLZ}	OE	ī	O _L = 50 pF	9	15.4	1	17.5	1	17.5	1	17.5	ns		
t _{sk(o)}			C _L = 50 pF		1.5 ⁽²⁾				1.5			ns		
t _{PLH}	A 0 = D	A or D	A or B	Y	$C_1 = 50 \text{ pF}$	6.3	8.8	1	10	1	10	1	10	ns
t _{PHL}	AUID	ī	O _L = 50 pr	6.3	8.8	1	10	1	10	1	10	115		

On products compliant to MIL-PRF-38535, this parameter is not production tested.

6.7 Switching Characteristics, $V_{CC} = 5 V \pm 0.5 V$

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 2)

PARAMETER	FROM	TO	LOAD T) CAPACITANCE	T _A = 25°C		SN54AHC541		SN74AHC541		T _A = -40°C to 125°C SN74AHC541		UNIT						
	(INPUT)	(OUTPUT)	CAPACITANCE	TYP	MAX	MIN	MAX	MIN	MAX	MIN	MAX							
t _{PLH}	^	Y	C - 15 5E	3.5 ⁽¹⁾	5 ⁽¹⁾	1 ⁽¹⁾	6 ⁽¹⁾	1	6	1	6	no						
t _{PHL}	Α	Ť	$C_L = 15 pF$	3.5 ⁽¹⁾	5 ⁽¹⁾	1 ⁽¹⁾	6 ⁽¹⁾	1	6	1	6	ns						
t _{PZH}	ŌĒ	Y	$C_1 = 15 pF$	4.7 ⁽¹⁾	7.2 ⁽¹⁾	1 ⁽¹⁾	8.5 ⁽¹⁾	1	8.5	1	8.5	ns						
t _{PZL}	OL	OE	ī	C _L = 15 pr	4.7 ⁽¹⁾	7.2 ⁽¹⁾	1 ⁽¹⁾	8.5 ⁽¹⁾	1	8.5	1	8.5	115					
t _{PHZ}	ŌĒ	Y	$C_1 = 15 pF$	5 ⁽¹⁾	7.5 ⁽¹⁾	1 ⁽¹⁾	8 ⁽¹⁾	1	8	1	8	ns						
t _{PLZ}	OE	'L '	OL = 13 pi	5 ⁽¹⁾	7.5 ⁽¹⁾	1 ⁽¹⁾	8 ⁽¹⁾	1	8	1	8	113						
t _{PLH}	^	^	Α	Y	C _ 50 sE	5	7	1	8	1	8	1	8	no				
t _{PHL}	A	ī	$C_L = 50 \text{ pF}$	5	7	1	8	1	8	1	8	ns						
t _{PZH}	ŌĒ	Y	$C_1 = 50 \text{ pF}$	6.2	9.2	1	10.5	1	10.5	1	10.5	ns						
t _{PZL}	OE	ī	C _L = 50 pr	6.2	9.2	1	10.5	1	10.5	1	10.5	115						
t _{PHZ}	OF	Y	$C_1 = 50 \text{ pF}$	6	8.8	1	10	1	10	1	10	no						
t _{PLZ}	OE	OE .	OE	OE	- OE	ŌĒ	Y	Y $C_L = 50 \text{ p}$	O _L = 50 pr	6	8.8	1	10	1	10	1	10	ns
t _{sk(o)}			C _L = 50 pF		1 (2)	1			1			ns						

On products compliant to MIL-PRF-38535, this parameter is not production tested. On products compliant to MIL-PRF-38535, this parameter does not apply.

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On products compliant to MIL-PRF-38535, this parameter does not apply.



6.8 Noise Characteristics

 $V_{CC} = 5 \text{ V}, C_L = 50 \text{ pF}, T_A = 25^{\circ}\text{C}^{(1)}$

	DADAMETED	SN74AH	LINUT	
	PARAMETER	MIN	MAX	UNIT
$V_{OL(P)}$	Quiet output, maximum dynamic V _{OL}		0.8	V
$V_{OL(V)}$	Quiet output, minimum dynamic V _{OL}		-0.8	V
$V_{OH(V)}$	Quiet output, minimum dynamic V _{OH}	4.7		V
$V_{IH(D)}$	High-level dynamic input voltage	3.5		V
$V_{IL(D)}$	Low-level dynamic input voltage		1.5	V

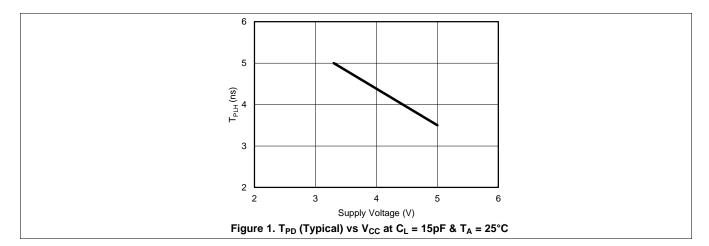
⁽¹⁾ Characteristics are for surface-mount packages only.

6.9 Operating Characteristics

 $V_{CC} = 5 \text{ V}, T_A = 25^{\circ}\text{C}$

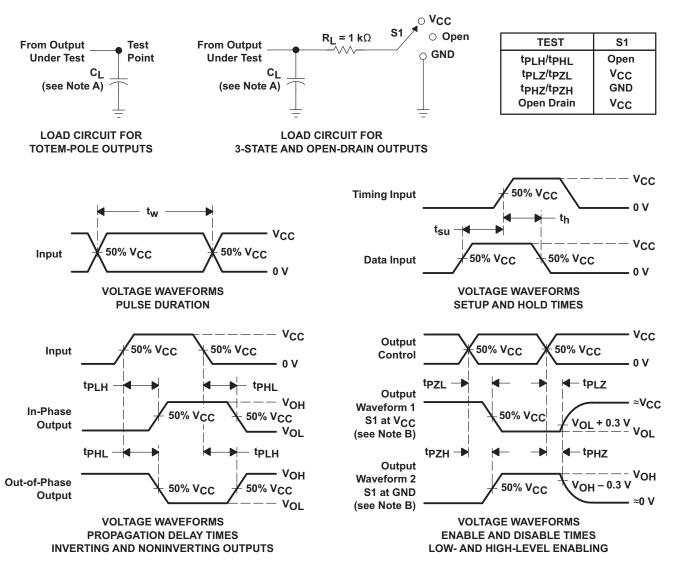
	PARAMETER	TEST C	CONDITIONS	TYP	UNIT
C_{pd}	Power dissipation capacitance	No load,	f = 1 MHz	12	pF

6.10 Typical Characteristics





7 Parameter Measurement Information



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, $Z_O = 50 \Omega$, $t_r \leq 3$ ns, $t_f \leq 3$ ns.
- D. The outputs are measured one at a time with one input transition per measurement.
- E. All parameters and waveforms are not applicable to all devices.

Figure 2. Load Circuit and Voltage Waveforms



Detailed Description

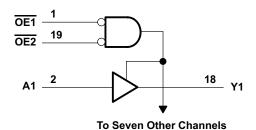
Overview 8.1

The SNx4AHC541 octal buffers/drivers are ideal for driving bus lines or buffer memory address registers. These devices feature inputs and outputs on opposite sides of the package to facilitate printed circuit board layout.

The 3-state control gate is a two-input AND gate with active-low inputs. If either output-enable (OE1 or OE2) input is high, all corresponding outputs are in the high-impedance state. The outputs provide noninverted data when they are not in the high-impedance state.

To ensure the high-impedance state during power up or power down, $\overline{\text{OE}}$ should be tied to V_{CC} through a pullup resistor. The minimum value of the resistor is determined by the current-sinking capability of the driver.

8.2 Functional Block Diagram



8.3 Feature Description

The SNx4AHC541 has a wide operating voltage range of 2 V to 5.5 V. It allows down voltage translations while accepting input voltages of up to 5.5 V. The slow edges of the SNx4AHC541 enables the reduction of output ringing.

8.4 Device Functional Modes

Table 1 lists the functional modes for the SNx4AHC541 devices.

Table 1. Function Table (Each Buffer/Driver)

	INPUTS	OUTPUT	
OE1	OE2	Α	Y
L	L	L	L
L	L	Н	Н
Н	Х	Х	Z
Х	Н	Х	Z

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9 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

9.1 Application Information

The SN74AHC541 is a low-drive CMOS device that can be used for a multitude of bus interface type applications where output ringing is a concern. The low drive and slow edge rates will minimize overshoot and undershoot on the outputs. The inputs accept voltages up to 5.5 V, which allows down translation to the V_{CC} level. Figure 4 shows how the slower edges can reduce ringing on the output compared to higher drive parts like AC.

9.2 Typical Application

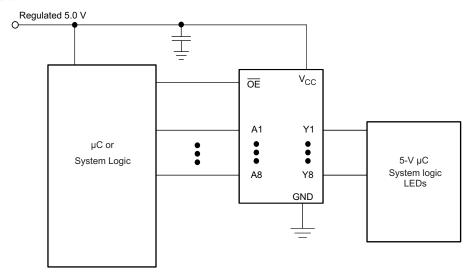


Figure 3. Typical Application Schematic

9.2.1 Design Requirements

This device uses CMOS technology and has balanced output drive. Take care to avoid bus contention because it can drive currents that would exceed maximum limits. The high drive will also create fast edges into light loads so routing and load conditions should be considered to prevent ringing.

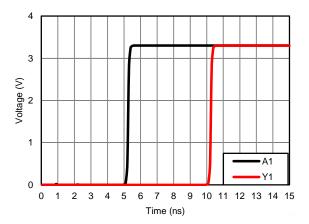
9.2.2 Detailed Design Procedure

- 1. Recommended Input Conditions:
 - For rise time and fall time specifications, see $\Delta t/\Delta V$ in the *Recommended Operating Conditions* table.
 - For specified high and low levels, see V_{IH} and V_{IL} in the Recommended Operating Conditions table.
 - Inputs are overvoltage tolerant allowing them to go as high as 5.5 V at any valid $V_{\rm CC}$
- 2. Recommended Output Conditions:
 - Load currents should not exceed 25 mA per output and 75 mA total for the part.
 - Outputs should not be pulled above V_{CC}.



Typical Application (continued)

9.2.3 Application Curve



 V_{cc} = 3.3 V, C_L = 15 pF, T_A = 25°C

Figure 4. Simulated Propagation Delay From Input (A1) to Output (Y1)

10 Power Supply Recommendations

The power supply can be any voltage between the minimum and maximum supply voltage rating located in the *Recommended Operating Conditions* table. Each V_{CC} terminal should have a good bypass capacitor to prevent power disturbance. For devices with a single supply, 0.1 μ F is recommended. If there are multiple V_{CC} terminals then 0.01 μ F or 0.022 μ F is recommended for each power terminal. It is acceptable to parallel multiple bypass caps to reject different frequencies of noise. A 0.1 μ F and 1 μ F are commonly used in parallel. The bypass capacitor should be installed as close to the power terminal as possible for best results.

11 Layout

11.1 Layout Guidelines

When using multiple bit logic devices, inputs should not float. In many cases, functions or parts of functions of digital logic devices are unused. Some examples are when only two inputs of a triple-input AND gate are used, or when only 3 of the 4-buffer gates are used. Such input pins should not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. Specified in the Figure 5 are rules that must be observed under all circumstances. All unused inputs of digital logic devices must be connected to a high or low bias to prevent them from floating. The logic level that should be applied to any particular unused input depends on the function of the device. Generally they will be tied to GND or V_{CC}, whichever makes more sense or is more convenient. It is acceptable to float outputs unless the part is a transceiver. If the transceiver has an output enable pin, it will disable the outputs section of the part when asserted. This will not disable the input section of the I/Os so they also cannot float when disabled.

11.2 Layout Example

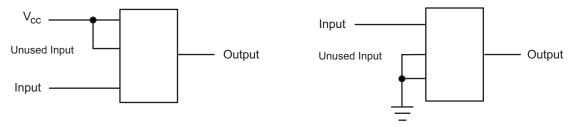


Figure 5. Layout Diagram



12 Device and Documentation Support

12.1 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

Table 2. Related Links

PARTS	PRODUCT FOLDER	SAMPLE & BUY	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY
SN74AHC541	Click here	Click here	Click here	Click here	Click here
SN54AHC541	Click here	Click here	Click here	Click here	Click here

12.2 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

TI E2E™ Online Community TI's Engineer-to-Engineer (E2E) Community. Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

12.3 Trademarks

E2E is a trademark of Texas Instruments.

All other trademarks are the property of their respective owners.

12.4 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

12.5 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.





22-Jul-2020

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
5962-9685701Q2A	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	5962- 9685701Q2A SNJ54AHC 541FK	Samples
5962-9685701QRA	ACTIVE	CDIP	J	20	1	TBD	SNPB	N / A for Pkg Type	-55 to 125	5962-9685701QR A SNJ54AHC541J	Samples
5962-9685701QSA	ACTIVE	CFP	W	20	1	TBD	Call TI	N / A for Pkg Type	-55 to 125	5962-9685701QS A SNJ54AHC541W	Samples
SN74AHC541DBR	ACTIVE	SSOP	DB	20	2000	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 125	HA541	Samples
SN74AHC541DBRG4	ACTIVE	SSOP	DB	20	2000	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 125	HA541	Samples
SN74AHC541DGVR	ACTIVE	TVSOP	DGV	20	2000	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 125	HA541	Samples
SN74AHC541DGVRG4	ACTIVE	TVSOP	DGV	20	2000	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 125	HA541	Samples
SN74AHC541DW	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AHC541	Samples
SN74AHC541DWR	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AHC541	Samples
SN74AHC541DWRE4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AHC541	Samples
SN74AHC541N	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	NIPDAU	N / A for Pkg Type	-40 to 125	SN74AHC541N	Samples
SN74AHC541NSR	ACTIVE	SO	NS	20	2000	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AHC541	Samples
SN74AHC541PW	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 125	HA541	Samples
SN74AHC541PWG4	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 125	HA541	Samples
SN74AHC541PWR	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	NIPDAU SN	Level-1-260C-UNLIM	-40 to 125	HA541	Samples



PACKAGE OPTION ADDENDUM

22-Jul-2020

Orderable Device	Status (1)	Package Type	Package Drawing		Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
SN74AHC541PWRE4	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 125	HA541	Samples
SN74AHC541PWRG4	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 125	HA541	Samples
SNJ54AHC541FK	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	5962- 9685701Q2A SNJ54AHC 541FK	Samples
SNJ54AHC541J	ACTIVE	CDIP	J	20	1	TBD	SNPB	N / A for Pkg Type	-55 to 125	5962-9685701QR A SNJ54AHC541J	Samples
SNJ54AHC541W	ACTIVE	CFP	W	20	1	TBD	Call TI	N / A for Pkg Type	-55 to 125	5962-9685701QS A SNJ54AHC541W	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.



PACKAGE OPTION ADDENDUM

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(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF SN54AHC541, SN74AHC541:

Catalog: SN74AHC541

Automotive: SN74AHC541-Q1, SN74AHC541-Q1

Military: SN54AHC541

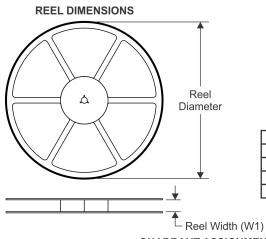
NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Automotive Q100 devices qualified for high-reliability automotive applications targeting zero defects
- Military QML certified for Military and Defense Applications

PACKAGE MATERIALS INFORMATION

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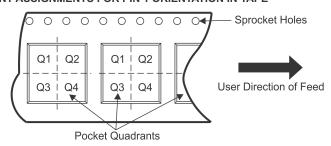
TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AHC541DBR	SSOP	DB	20	2000	330.0	16.4	8.2	7.5	2.5	12.0	16.0	Q1
SN74AHC541DGVR	TVSOP	DGV	20	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74AHC541DWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1
SN74AHC541NSR	SO	NS	20	2000	330.0	24.4	8.4	13.0	2.5	12.0	24.0	Q1
SN74AHC541PWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1
SN74AHC541PWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.0	1.4	8.0	16.0	Q1
SN74AHC541PWRG4	TSSOP	PW	20	2000	330.0	16.4	6.95	7.0	1.4	8.0	16.0	Q1

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*All dimensions are nominal

	-						
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74AHC541DBR	SSOP	DB	20	2000	367.0	367.0	38.0
SN74AHC541DGVR	TVSOP	DGV	20	2000	367.0	367.0	35.0
SN74AHC541DWR	SOIC	DW	20	2000	367.0	367.0	45.0
SN74AHC541NSR	SO	NS	20	2000	367.0	367.0	45.0
SN74AHC541PWR	TSSOP	PW	20	2000	364.0	364.0	27.0
SN74AHC541PWR	TSSOP	PW	20	2000	367.0	367.0	38.0
SN74AHC541PWRG4	TSSOP	PW	20	2000	367.0	367.0	38.0

W (R-GDFP-F20)

CERAMIC DUAL FLATPACK



- A. All linear dimensions are in inches (millimeters).
- This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a ceramic lid using glass frit.

 D. Index point is provided on cap for terminal identification only.

 E. Falls within Mil—Std 1835 GDFP2—F20



FK (S-CQCC-N**)

LEADLESS CERAMIC CHIP CARRIER

28 TERMINAL SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a metal lid.
- D. Falls within JEDEC MS-004





SMALL OUTLINE PACKAGE



- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-150.



SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



MECHANICAL DATA

NS (R-PDSO-G**)

14-PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



14 LEADS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

DGV (R-PDSO-G**)

24 PINS SHOWN

PLASTIC SMALL-OUTLINE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.

D. Falls within JEDEC: 24/48 Pins – MO-153 14/16/20/56 Pins – MO-194 PW (R-PDSO-G20)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
- E. Falls within JEDEC MO-153



PW (R-PDSO-G20)

PLASTIC SMALL OUTLINE



- All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.C. Publication IPC-7351 is recommended for alternate design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.





SOIC



- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



SOIC



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOIC



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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